NSN 5961-01-019-2174

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-019-2174 **Inclosure Material:** Metal **Overall Length:** Between 1.248 inches and 1.252 inches **Overall Height:** 0.285 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 collector to emitter voltage/static/base open and 200.0 collector to base voltage/static/emitter open and 200.0 collector-to-emitter, resistance between base and emitter and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No